P-Channel Enhancement-Mode Vertical DMOS FET

Features

- Free from secondary breakdown
- Low power drive requirement
- Ease of paralleling
- Low C_{ISS} and fast switching speeds
- High input impedance and high gain
- Excellent thermal stability
- Integral source-to-drain diode

Applications

- Motor controls
- Converters, amplifiers, and switches
- Power supply circuits
- Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

General Description

The Supertex VP2206 is an enhancement-mode (normally-off) transistor that utilizes a vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors, and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Ordering Information

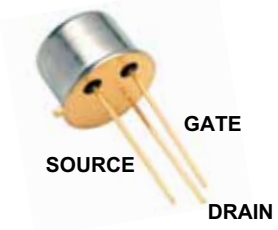
Part Number	Package Option	Packing
VP2206N2-G	TO-39	500/Bag
VP2206N3-G	TO-92	1000/Bag
VP2206N3-G P002	TO-92	2000/Reel
VP2206N3-G P003		
VP2206N3-G P005		
VP2206N3-G P013		
VP2206N3-G P014		

-G denotes a lead (Pb)-free / RoHS compliant package.
Contact factory for Wafer / Die availablity.
Devices in Wafer / Die form are lead (Pb)-free / RoHS compliant.

Product Summary

BV_{DSS}/BV_{DGS}	$R_{DS(ON)}$ (max)	$I_{D(ON)}$ (min)
-60V	0.9Ω	-4.0A

Pin Configuration



TO-39



TO-92

Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	BV_{DSS}
Drain-to-gate voltage	BV_{DGS}
Gate-to-source voltage	±20V
Operating and storage temperature	-55°C to +150°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

Typical Thermal Resistance

Package	θ_{ja}
TO-39	N/A
TO-92	132°C/W

Product Marking



YY = Year Sealed
WW = Week Sealed

Package may or may not include the following marks: Si or

TO-39



YY = Year Sealed
WW = Week Sealed
_____ = "Green" Packaging

Package may or may not include the following marks: Si or

TO-92

Thermal Characteristics

Package	I_D (continuous)†	I_D (pulsed)	Power Dissipation @T_C = 25°C	I_{DR}†	I_{DRM}
TO-39	-750mA	-8.0A	0.36W	-750mA	-8.0A
TO-92	-640mA	-4.0	0.74W	-640mA	-4.0

Notes:

† *I_D (continuous) is limited by max rated T_j.*

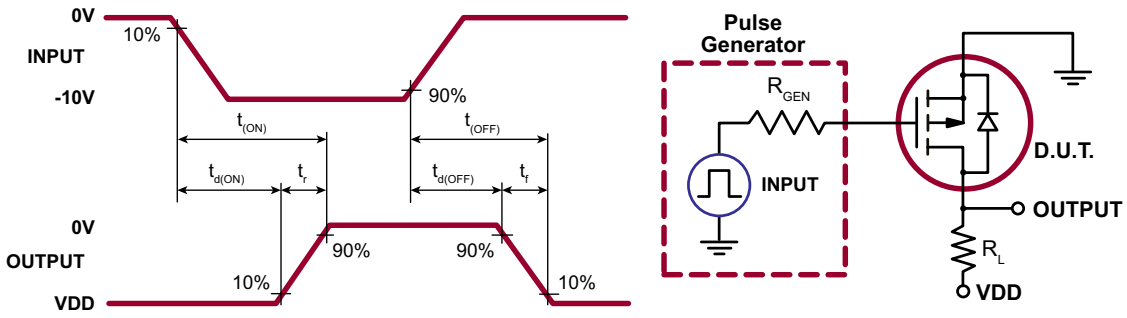
Electrical Characteristics *(T_A = 25°C unless otherwise specified)*

Sym	Parameter	Min	Typ	Max	Units	Conditions
BV_{DSS}	Drain-to-source breakdown voltage	-60	-	-	V	V_{GS} = 0V, I_D = -10mA
$V_{GS(th)}$	Gate threshold voltage	-1.0	-	-3.5	V	V_{GS} = V_{DS}, I_D= -10mA
$\Delta V_{GS(th)}$	Change in $V_{GS(th)}$ with temperature	-	-4.3	-5.5	mV/°C	V_{GS} = V_{DS}, I_D= -10mA
I_{GSS}	Gate body leakage	-	-1.0	-100	nA	V_{GS} = ± 20V, V_{DS} = 0V
I_{DSS}	Zero gate voltage drain current	-	-	-50	µA	V_{GS} = 0V, V_{DS} = Max Rating
		-	-	-10	mA	V_{DS} = 0.8 Max Rating, V_{GS} = 0V, T_A = 125°C
$I_{D(ON)}$	On-state drain current	-0.85	-2.0	-		V_{GS} = -5.0V, V_{DS} = -25V
		-4.0	-9.0	-	A	V_{GS} = -10V, V_{DS} = -25V
$R_{DS(ON)}$	Static drain-to-source on-state resistance	-	1.3	1.5	Ω	V_{GS} = -5.0V, I_D = -1.0A
		-	0.75	0.9		V_{GS} = -10V, I_D = -3.5A
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with temperature	-	0.85	1.2	%/°C	V_{GS} = -10V, I_D = -3.5A
G_{FS}	Forward transductance	800	1400	-	mmho	V_{DS} = -25V, I_D = -2.0A
C_{ISS}	Input capacitance	-	325	450	pF	V_{GS} = 0V, V_{DS} = -25V, f = 1.0MHz
C_{OSS}	Common source output capacitance	-	125	180		
C_{RSS}	Reverse transfer capacitance	-	30	40		
$t_{d(ON)}$	Turn-on delay time	-	4.0	15	ns	V_{DD} = -25V, I_D = -4.0A, R_{GEN} = 10Ω
t_r	Rise time	-	16	25		
$t_{d(OFF)}$	Turn-off delay time	-	16	50		
t_f	Fall time	-	22	50		
V_{SD}	Diode forward voltage drop	-	-1.1	-1.6	V	V_{GS} = 0V, I_{SD} = -3.5A
t_{rr}	Reverse recovery time	-	500	-	ns	V_{GS} = 0V, I_{SD} = -1.0A

Notes:

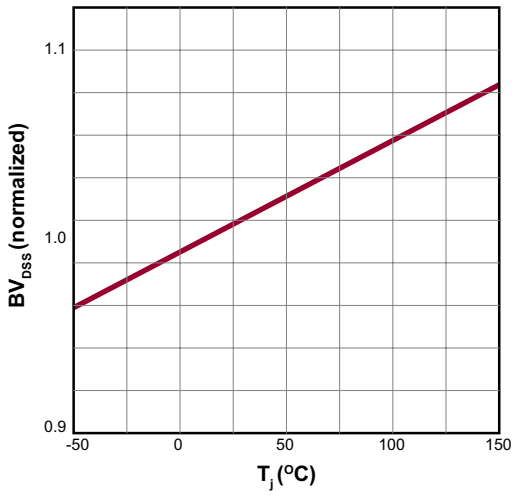
1. *All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)*
2. *All A.C. parameters sample tested.*

Switching Waveforms and Test Circuit

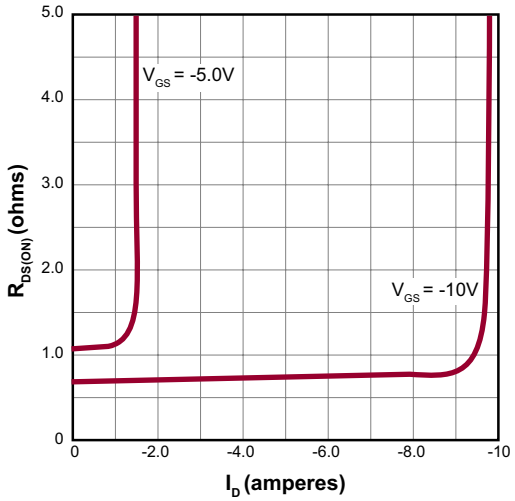


Typical Performance Curves

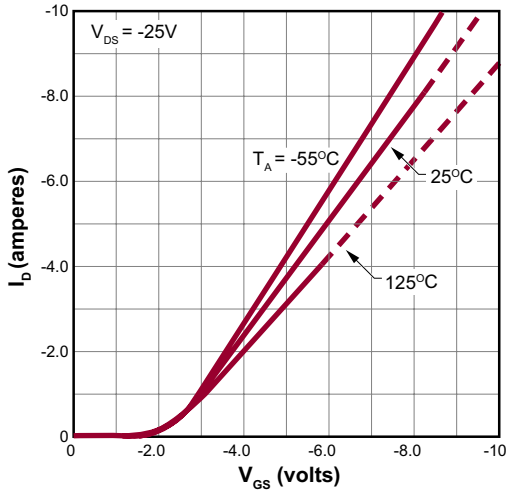
BV_{DSS} Variation with Temperature



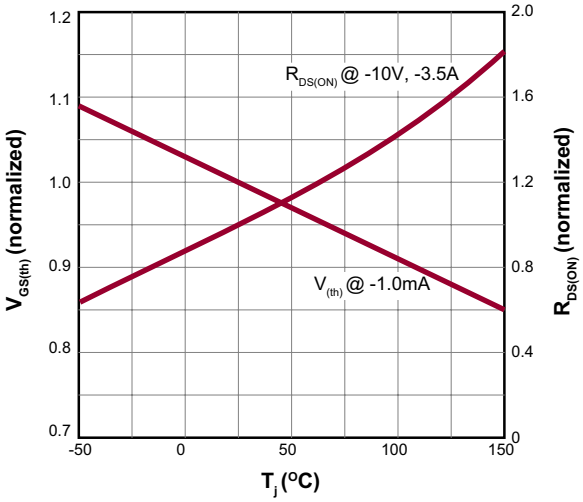
On-Resistance vs. Drain Current



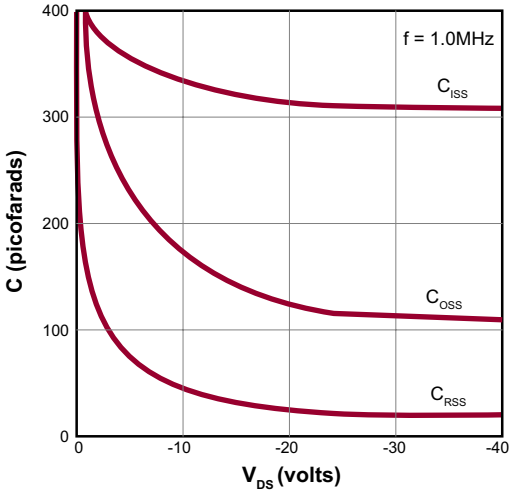
Transfer Characteristics



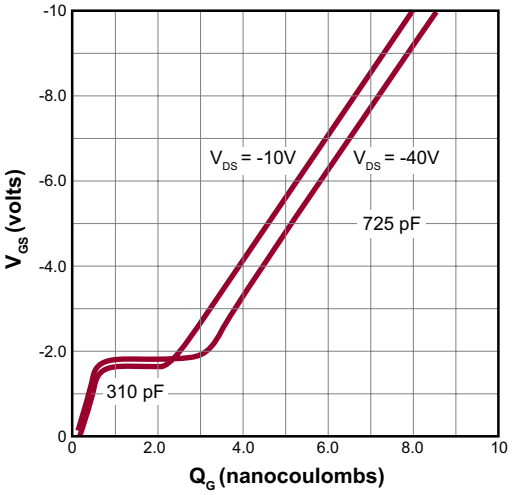
$V_{(th)}$ and R_{DS} Variation with Temperature



Capacitance vs. Drain-to-Source Voltage

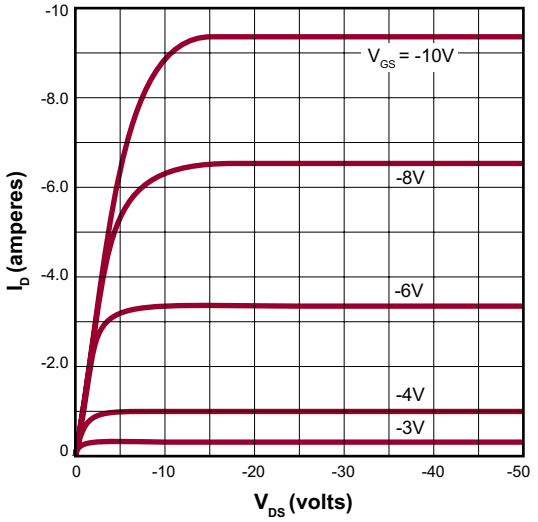


Gate Drive Dynamic Characteristics

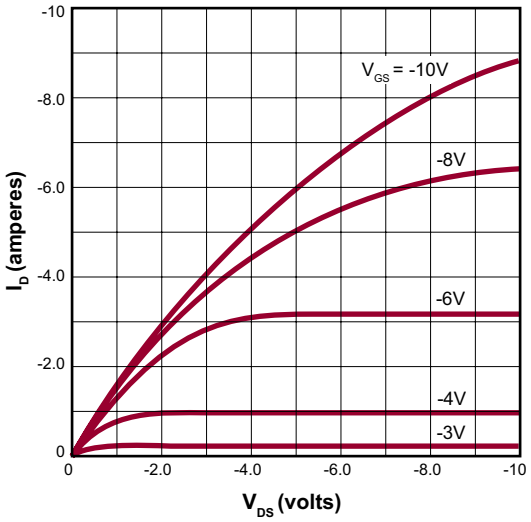


Typical Performance Curves *(cont.)*

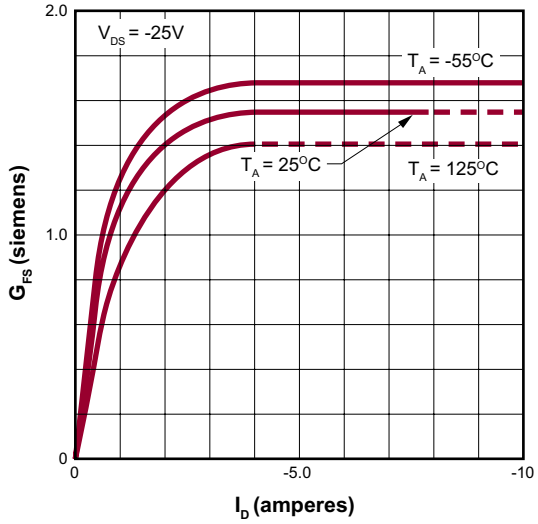
Output Characteristics



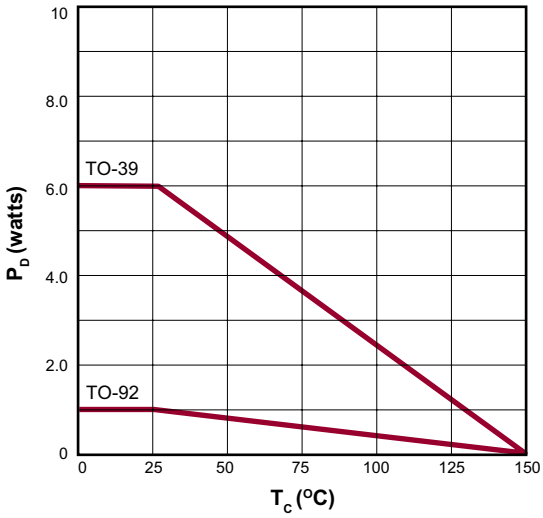
Saturation Characteristics



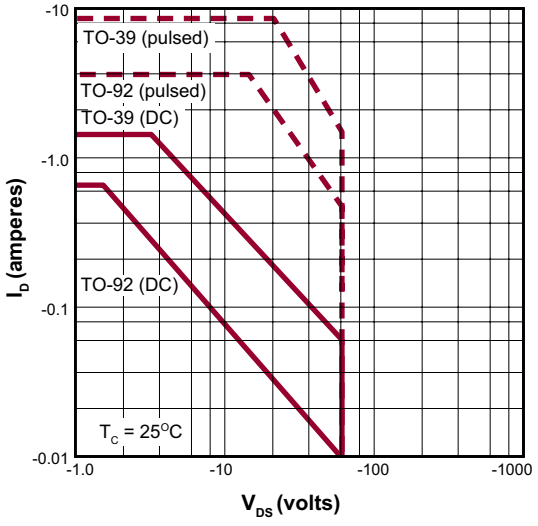
Transconductance vs. Drain Current



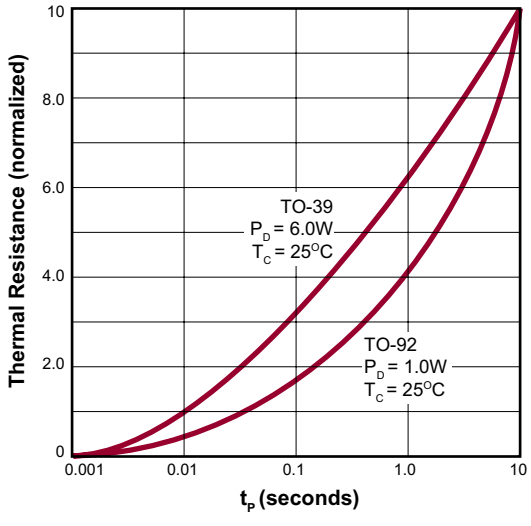
Power Dissipation vs. Case Temperature



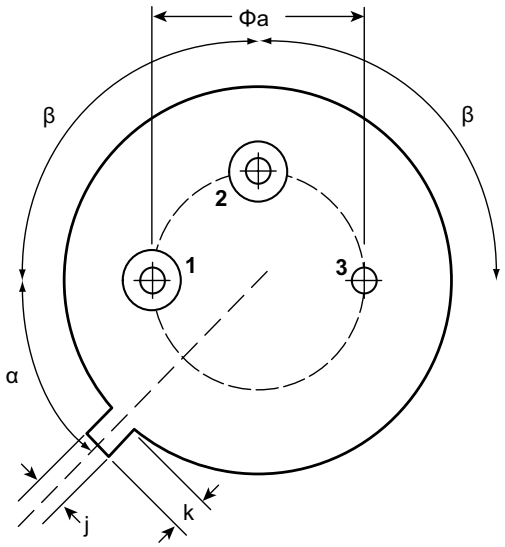
Maximum Rated Safe Operating Area



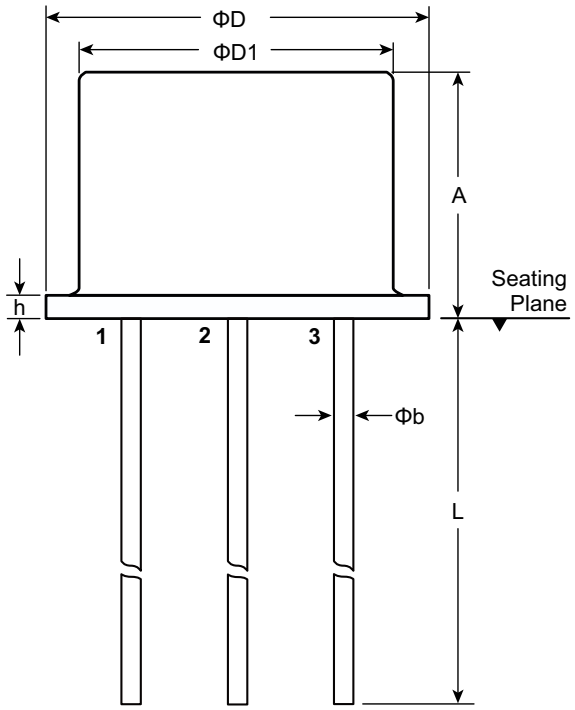
Thermal Response Characteristics



3-Lead TO-39 Package Outline (N2)



Bottom View

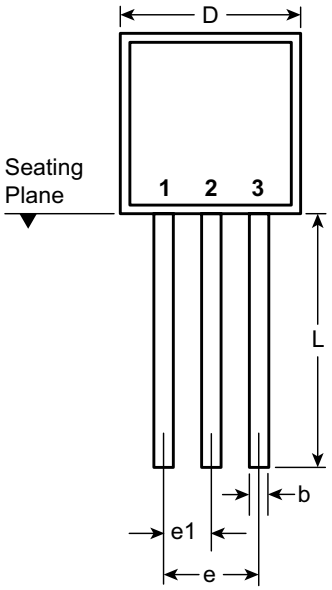


Side View

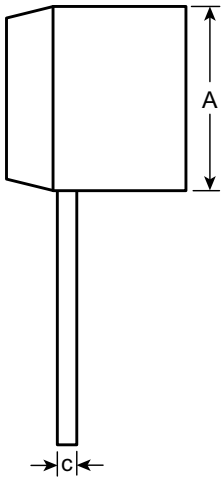
Symbol		α	β	A	Φa	Φb	ΦD	ΦD1	h	j	k	L
Dimension (inches)	MIN	45° NOM	90° NOM	.240	.190	.016	.350	.315	.009	.028	.029	.500
	NOM			-	-	-	-	-	-	-	-	-
	MAX			.260	.210	.021	.370	.335	.125	.034	.040	.560*

JEDEC Registration TO-39.
** This dimension is not specified in the JEDEC drawing.*
Drawings not to scale.
***Supertex Doc. #:** DSPD-3TO39N2, Version B052009.*

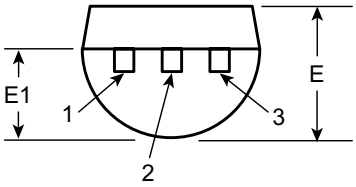
3-Lead TO-92 Package Outline (N3)



Front View



Side View



Bottom View

Symbol		A	b	c	D	E	E1	e	e1	L
Dimensions (inches)	MIN	.170	.014†	.014†	.175	.125	.080	.095	.045	.500
	NOM	-	-	-	-	-	-	-	-	-
	MAX	.210	.022†	.022†	.205	.165	.105	.105	.055	.610*

JEDEC Registration TO-92.
** This dimension is not specified in the JEDEC drawing.*
† This dimension differs from the JEDEC drawing.
Drawings not to scale.
***Supertex Doc.#:** DSPD-3TO92N3, Version E041009.*

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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